



## T15DA-RYZ-W-I 1550nm DFB Laser Diode, TOSA Receptacle

### Description

The Lasermate T15DA-RYZ-W-I is an Analog 1550nm wavelength, Distributed Feedback (DFB) laser diode in receptacle package with output power up to >2mW and isolator. The laser is designed for use in wireless and analog applications.



### Features

- InGaAsP/InP MQW-DFB laser diode (LD)
- Data Rate: 155Mbps up to 2.5Gbps
- Uncooled operation at -20 to 85°C
- Hermetically sealed active component
- Built-in high performance, high speed InGaAs monitor PIN photodiode (PD)
- With single-stage isolator

### Packaging

- FC/ST receptacle package with 2-hole flange

### Applications

- ATM/SONET OC-3/OC-12/OC-24
- SDH STM-1/STM-4/STM-8
- Gigabit Ethernet
- Wireless (CDMA, GSM, PCS) and Analog applications

### Ordering Information

<b>Read Model No.</b>	<b>T15DA-RYZ-W-I</b>
T15DA = Laser	Analog 1510nm DFB laser
R = Package	Receptacle
Y = Connector	FC ( <b>FC</b> ); ST ( <b>ST</b> )
Z = Output power	>1mW ( <b>H</b> ); >2mW ( <b>2</b> )
W = Pin configuration	A pinout ( <b>A</b> )
I = Isolator	With isolator ( <b>I</b> )



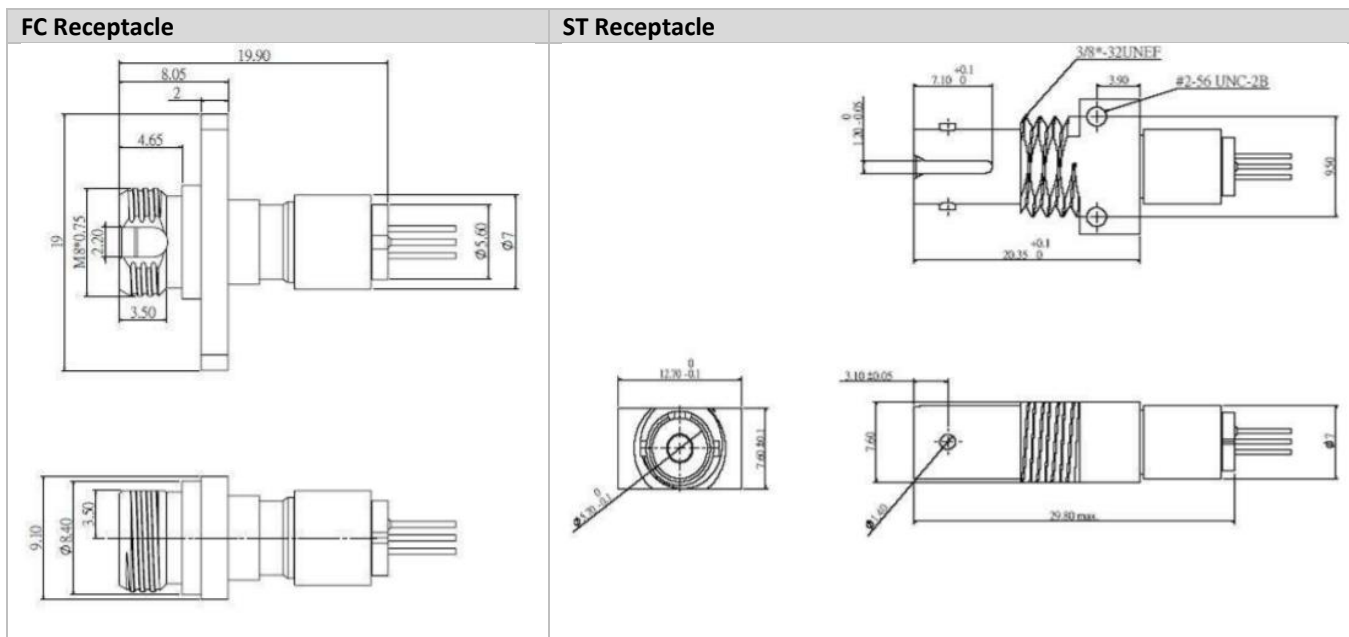
## Specifications

Absolute Maximum Ratings				
Parameters	Symbol	Value	Unit	Conditions
Storage temperature	Tstg	-40 to +85	°C	
Operating case temperature	Top	-20 to +85	°C	
Peak optical output power	Po	5	mW	
Forward current (LD)	I <sub>FLD</sub>	100	mA	
Reverse voltage (LD)	V <sub>RLD</sub>	2	V	
Reverse current (PD)	I <sub>RPD</sub>	5	mA	
Reverse voltage (PD)	V <sub>RPD</sub>	15	V	
Soldering temperature	Stemp	260	°C	10 seconds

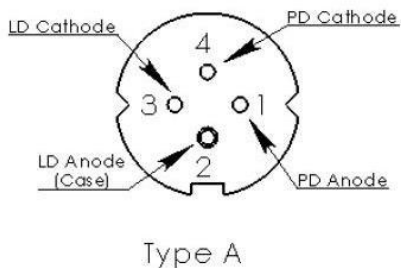
Electro-Optical Characteristics (CW @ T <sub>c</sub> = 25°C unless otherwise noted)						
Parameters	Symbol	Min.	Typ.	Max.	Unit	Conditions
Central wavelength	$\lambda_c$	1540	1550	1560	nm	CW, Pf
Side mode suppression ratio	SMSR	30	40	-	dB	Pf
Spectral width	$\Delta\lambda$	-	0.2	1	nm	Pf
Threshold current	I <sub>th</sub>	-	10	15	mA	CW
Fiber output power	Pf	1.0			mW	CW, I <sub>f</sub> =I <sub>th</sub> +20mA
		2.0				
Operating voltage	V <sub>op</sub>	-	1.1	1.5	V	Pf
Rise time / Fall time	t <sub>r</sub> /t <sub>f</sub>	-	0.1	0.2	nsec	I <sub>b</sub> = I <sub>th</sub> , 20%~80%
Monitor current	I <sub>m</sub>	100	-	1000	uA	Pf, V <sub>rp</sub> =5V
Monitor dark current	I <sub>d</sub>	-	0.1	100	nA	V <sub>rp</sub> =5V
Monitor capacitance	C	-	10	20	pF	V <sub>rp</sub> =5V, f=1MHz
Relative intensity noise	RIN	-	-154	-145	dB/Hz	CW, P <sub>op</sub> =2.0mW, f=2200MHz
Second-order intermodulation	IMD2	-	-	-45	dBc	Two-tone, OMI=20%/tone, f=2200MHz & 2202.5MHz
Third-order intermodulation	IMD3	-	-	-56	dBc	Two-tone, OMI=20%/tone, f=2200MHz & 2202.5MHz
Tracking error*	$\Delta Pf / Pf$	-	±1.0	±1.5	dB	APC, T <sub>c</sub> =-40~+85°C

\*I<sub>m</sub>=constant @ Pf, T<sub>c</sub>=25 °C

### Outline Dimensions (unit: mm)



### Pin Assignment



Pin Number	Type A
1	PD Anode
2	LD Anode (case)
3	LD Cathode
4	PD Cathode

### Additional Notes

- Avoid eye or skin exposure to laser radiations.
- The device is sensitive to electro-static discharge (ESD). The device should be handled with ESD proof tools. To assemble the device on PCB, proper grounding is required to prevent ESD.
- Specifications are subject to change without notice.